



N-Channel 30-V (D-S) Fast Switching MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$ $I_{D}(A$				
30	0.0065 at V _{GS} = 10 V	21			
	0.008 at V _{GS} = 4.5 V	19			

FEATURES

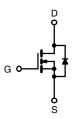
- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFET
- New Low Thermal Resistance PowerPAK[®] Package with Low 1.07 mm Profile
- 100 % R_a Tested





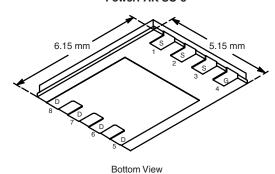
APPLICATIONS

- DC/DC Converters
- Optimized for "Low-Side" Synchronous Rectifier Operation



N-Channel MOSFET

PowerPAK SO-8



Ordering Information: Si7440DP-T1-E3 (Lead (Pb)-free)

Si7440DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	30		٧	
Gate-Source Voltage		V_{GS}	± 20			
Continuous Drain Current (T _{.I} = 150°C) ^a	T _A = 25°C	- I _D	21	12	A	
Continuous Diam Curient (1) = 150 C)	T _A = 70°C		17	9		
Pulsed Drain Current		I _{DM}	60		A	
Continuous Source Current (Diode Conduction) ^a		I _S	4.3	1.6		
Maximum Power Dissipation ^a	T _A = 25°C	P _D	5.4	1.9	W	
Maximum Fower Dissipation	T _A = 70°C		3.4	1.2	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature) ^{b, c}			260			

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Management to the Aughternia	t ≤ 10 s	- R _{thJA}	18	23	°C/W	
Maximum Junction-to-Ambient ^a	Steady State		52	65		
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	1.0	1.3		

Notes

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (<u>www.vishay.com/ppg?73257</u>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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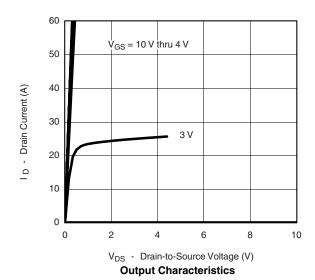
Parameter	Symbol	Test Conditions		Тур.	Max.	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0		3.0	V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±20 V			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1	
		V _{DS} = 30 V, V _{GS} = 0 V, T _J = 55°C			5	μΑ
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α
Drain-Source On-State Resistance ^a	В	V _{GS} = 10 V, I _D = 21 A		0.0053	0.0065	Ω
	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 19 \text{ A}$	S = 4.5 V, I _D = 19 A 0.0065		0.008	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 21 A		65		S
Diode Forward Voltage ^a	V_{SD}	I _S = 4.3 A, V _{GS} = 0 V		0.72	1.2	V
Dynamic ^b	<u> </u>		•			
Total Gate Charge	Q_g			29.0	35	
Gate-Source Charge	Q_{gs} $V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 21 \text{ A}$ Q_{gd}		10.5		nC	
Gate-Drain Charge				10.0		
Gate Resistance	R_{g}		0.5	1.4	2.2	Ω
Turn-On Delay Time	t _{d(on)}			18	28	
Rise Time	$\begin{array}{c} t_r \\ \\ t_{d(off)} \end{array} \hspace{0.2in} V_{DD} = 15 \text{ V}, \ R_L = 15 \ \Omega \\ \\ I_D \cong 1.0 \text{ A}, \ V_{GEN} = 10 \text{ V}, \ R_g = 6 \ \Omega \end{array}$		16	25	ns	
Turn-Off Delay Time			75	180		
Fall Time	t _f			41	65	
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = 4.3 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		50	80	

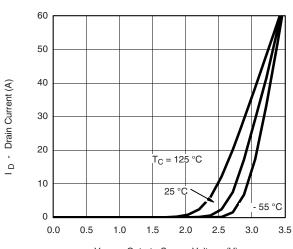
Notes

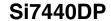
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



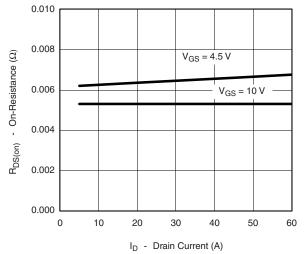




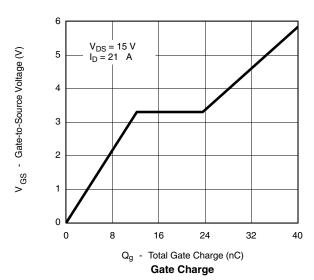


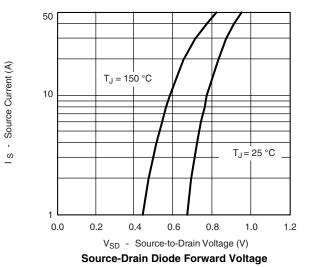


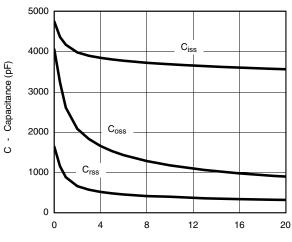
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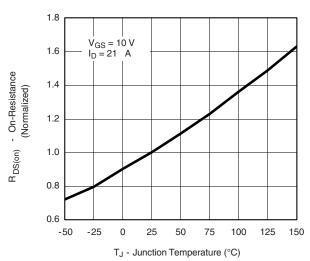
On-Resistance vs. Drain Current



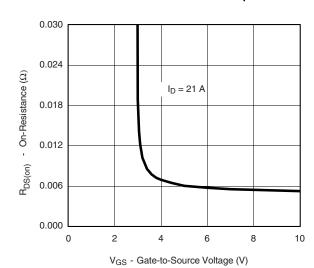




V_{DS} - Drain-to-Source Voltage (V) **Capacitance**



On-Resistance vs. Junction Temperature

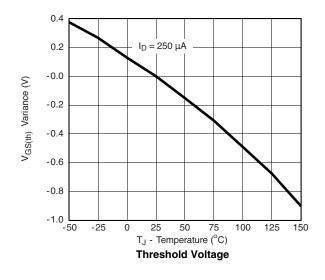


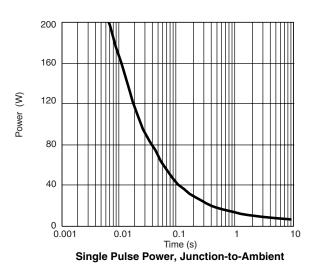
On-Resistance vs. Gate-to-Source Voltage

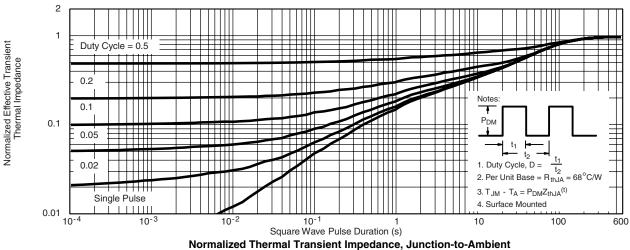
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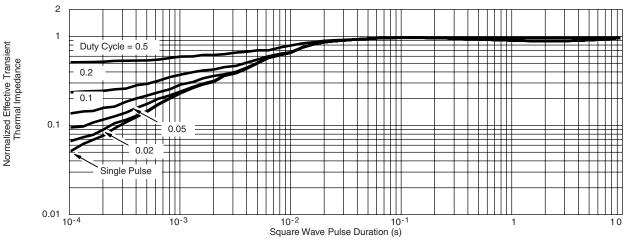
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted









Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71623.



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